## **MBR1060**

# **SWITCHMODE** <sup>™</sup> **Power Rectifiers**

#### **Features**

- Guard-Ring for Stress Protection
- Low Forward Voltage
- 175°C Operating Junction Temperature
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Low Power Loss/High Efficiency
- High Surge Capacity
- Low Stored Charge Majority Carrier Conduction
- Pb-Free Packages are Available\*

#### **Mechanical Characteristics**

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- ESD Rating: Human Body Model = 3B

Machine Model = C



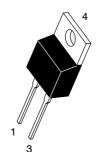
#### ON Semiconductor®

http://onsemi.com

### SCHOTTKY BARRIER RECTIFIERS 10 AMPERES, 60 VOLTS



#### MARKING DIAGRAM



TO-220AC CASE 221B PLASTIC



A = Assembly Location

= Year

WW = Work Week
G = Pb-Free Package
B1060 = Device Code
KA = Diode Polarity

#### **ORDERING INFORMATION**

Device	Package	Shipping
MBR1060	TO-220	50 Units/Rail
MBR1060G	TO-220 (Pb-Free)	50 Units/Rail

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **MBR1060**

#### **MAXIMUM RATINGS**

Rating	Symbol	MBR1060	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	60	V
Average Rectified Forward Current (Rated V <sub>R</sub> ) T <sub>C</sub> = 133°C	I <sub>F(AV)</sub>	10	Α
Peak Repetitive Forward Current (Rated V <sub>R</sub> , Square Wave, 20 kHz) T <sub>C</sub> = 133°C	I <sub>FRM</sub>	20	А
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	150	А
Peak Repetitive Reverse Surge Current (2.0 μs, 1.0 kHz)	I <sub>RRM</sub>	0.5	Α
Operating Junction Temperature (Note 1)	TJ	- 65 to +175	°C
Storage Temperature	T <sub>stg</sub>	- 65 to +175	°C
Voltage Rate of Change (Rated V <sub>R</sub> )	dv/dt	10,000	V/μs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### THERMAL CHARACTERISTICS

Maximum Thermal Resistance, Junction-to-Case	$R_{ hetaJC}$	2.0	°C/W
Maximum Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	60	°C/W
ELECTRICAL CHARACTERISTICS			
Maximum Instantaneous Forward Voltage (Note 2) (i <sub>F</sub> = 10 Amps, T <sub>C</sub> = 125°C)	VF	0.7	V
(i <sub>F</sub> = 10 Amps, $T_C$ = 25°C) (i <sub>F</sub> = 20 Amps, $T_C$ = 125°C)		0.8 0.85	
(i <sub>F</sub> = 20 Amps, T <sub>C</sub> = 25°C)		0.95	

 $i_R$ 

 $\mathsf{m}\mathsf{A}$ 

22

0.10

Maximum Instantaneous Reverse Current (Note 2)

(Rated dc Voltage,  $T_C = 125^{\circ}C$ )

(Rated dc Voltage, T<sub>C</sub> = 25°C)

<sup>1.</sup> The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

<sup>2.</sup> Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

#### **MBR1060**

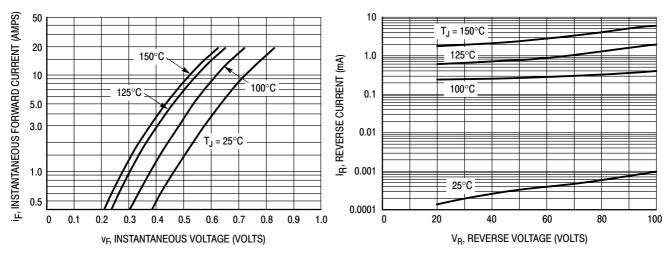


Figure 1. Typical Forward Voltage

Figure 2. Typical Reverse Current

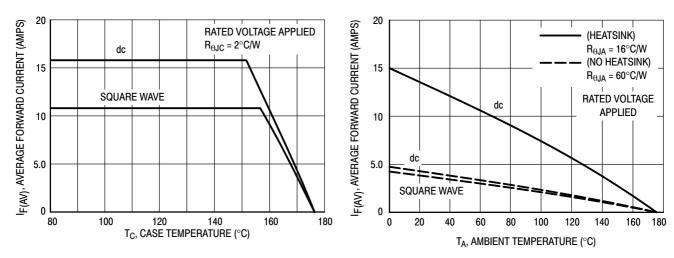


Figure 3. Typical Current Derating, Case

Figure 4. Typical Current Derating, Ambient

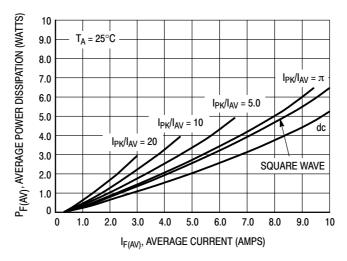


Figure 5. Forward Power Dissipation

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# **MECHANICAL CASE OUTLINE**

**PACKAGE DIMENSIONS** 



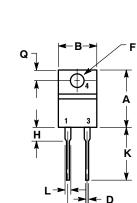


TO-220, 2-LEAD CASE 221B-04 ISSUE F

**DATE 12 APR 2013** 

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

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	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.595	0.620	15.11	15.75
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.82
D	0.025	0.039	0.64	1.00
F	0.142	0.161	3.61	4.09
G	0.190	0.210	4.83	5.33
Н	0.110	0.130	2.79	3.30
J	0.014	0.025	0.36	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.14	1.52
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.14	1.39
T	0.235	0.255	5.97	6.48
U	0.000	0.050	0.000	1.27



STYLE 1: PIN 1. CATHODE 2. N/A 3. ANODE

PIN 1. ANODE 2. N/A 3. CATHODE 4. ANODE

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